



# PJN1NA60A / PJW1NA60A / PJU1NA60A / PJD1NA60A

## 600V N-Channel MOSFET

**Voltage**

**600 V**

**Current**

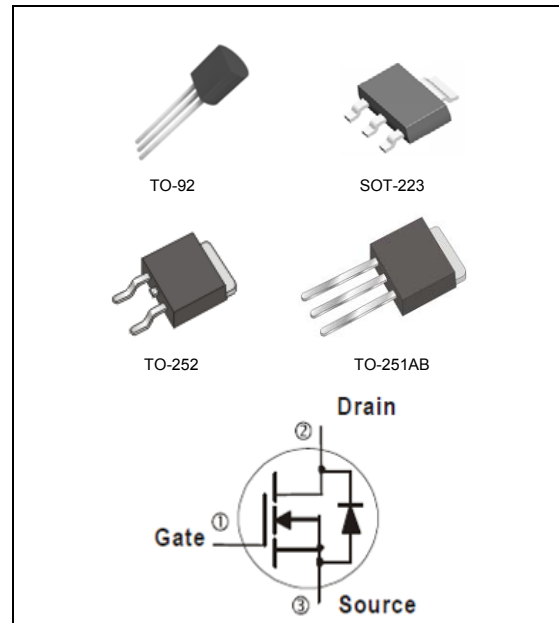
**1 A**

### Features

- $R_{DS(ON)}, V_{GS}@10V, I_D@0.5A < 7.9\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### Mechanical Data

- Case : TO-251AB, TO-252, SOT-223, TO-92 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-251AB Approx. Weight : 0.0104 ounces, 0.297grams
- TO-252 Approx. Weight : 0.0104 ounces, 0.297grams
- SOT-223 Approx. Weight : 0.043 ounces, 0.123grams
- TO-92 Approx. Weight : 0.007 ounces, 0.196grams



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	TO-251AB/TO-252	SOT-223	TO-92	UNITS
Drain-Source Voltage		$V_{DS}$	600			V
Gate-Source Voltage		$V_{GS}$	+30			V
Continuous Drain Current		$I_D$	1	0.4		A
Pulsed Drain Current		$I_{DM}$	4	1.6		A
Single Pulse Avalanche Energy <sup>(Note 1)</sup>		$E_{AS}$	52			mJ
Power Dissipation	$T_C=25^\circ\text{C}$	$P_D$	28	3.3	3	W
	Derate above $25^\circ\text{C}$		0.22	0.026	0.024	W/ $^\circ\text{C}$
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150			$^\circ\text{C}$
Typical Thermal resistance						$^\circ\text{C/W}$
- Junction to Case		$R_{\theta JC}$	4.46	-	-	
- Junction to Ambient		$R_{\theta JA}$	110	37.9 <sup>(Note 4)</sup>	140	

- Limited only By Maximum Junction Temperature



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	600	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	2	3.3	4	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=0.5A$	-	7.2	7.9	$\Omega$
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=600V, V_{GS}=0V$	-	0.02	1.0	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 30V, V_{DS}=0V$	-	$\pm 10$	$\pm 100$	nA
Diode Forward Voltage	$V_{SD}$	$I_S=1A, V_{GS}=0V$	-	0.88	1.4	V
<b>Dynamic</b> (Note 5)						
Total Gate Charge	$Q_g$	$V_{DS}=480V, I_D=1A,$ $V_{GS}=10V$ (Note 2,3)	-	3.1	-	nC
Gate-Source Charge	$Q_{gs}$		-	1.3	-	
Gate-Drain Charge	$Q_{gd}$		-	0.4	-	
Input Capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V,$ $f=1.0\text{MHz}$	-	148	-	pF
Output Capacitance	$C_{oss}$		-	28	-	
Reverse Transfer Capacitance	$C_{rss}$		-	0.3	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=300V, I_D=1A,$ $R_G=25\Omega$ (Note 2,3)	-	6	-	ns
Turn-On Rise Time	$t_r$		-	20	-	
Turn-Off Delay Time	$t_{d(off)}$		-	9	-	
Turn-Off Fall Time	$t_f$		-	26	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	1	A
Maximum Pulsed Drain-Source Diode Forward Current	$I_{SM}$	---	-	-	4	A
Reverse Recovery Time	$t_{rr}$	$V_{GS}=0V, I_S=1A$	-	190	-	ns
Reverse Recovery Charge	$Q_{rr}$	$di_F/dt=100A/\mu s$ (Note 2)	-	0.53	-	$\mu C$

**NOTES :**

1.  $L=30\text{mH}, I_{AS}=1.8A, V_{DD}=50V, R_G=25\text{ohm}$ , Starting  $T_J=25^\circ\text{C}$
2. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
3. Essentially independent of operating temperature typical characteristics
4.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
5. Guaranteed by design, not subject to production testing



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## TYPICAL CHARACTERISTIC CURVES

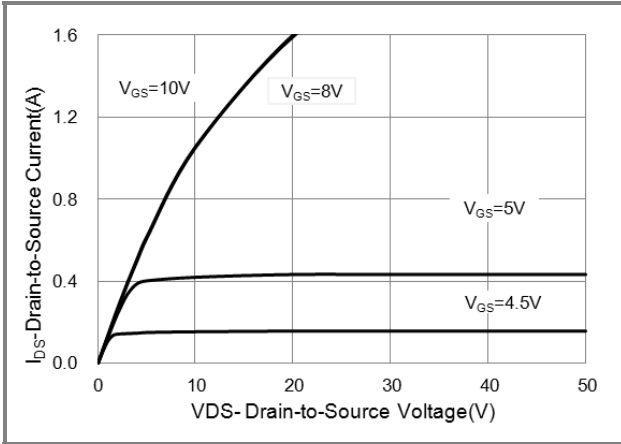


Fig.1 Output Characteristics

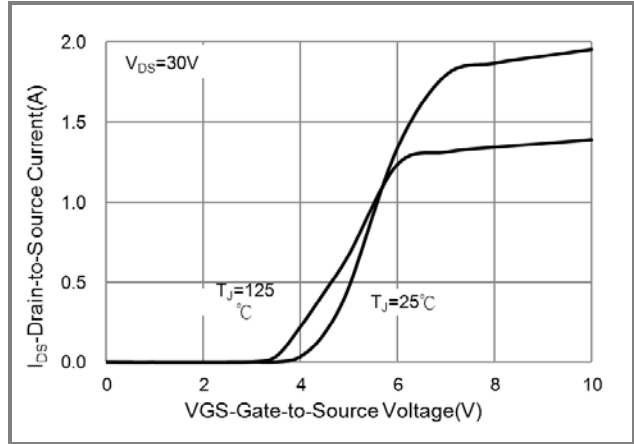


Fig.2 Transfer Characteristics

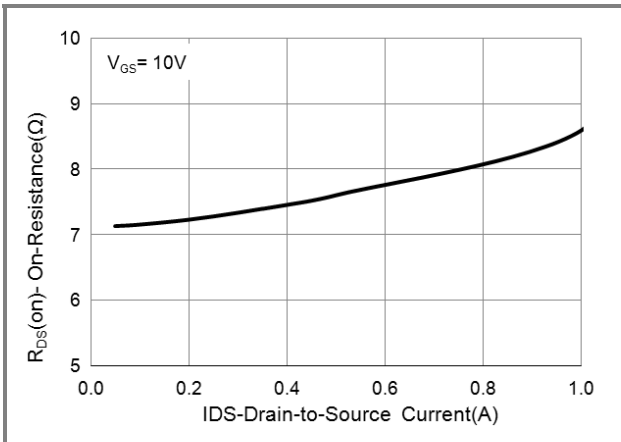


Fig.3 On-Resistance vs. Drain Current

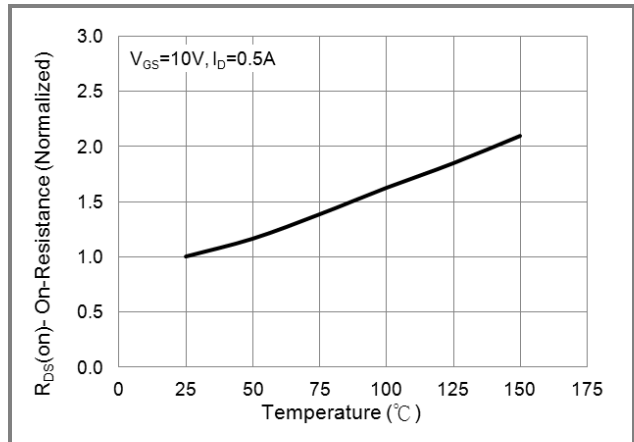


Fig.4 On-Resistance vs. Junction Temperature

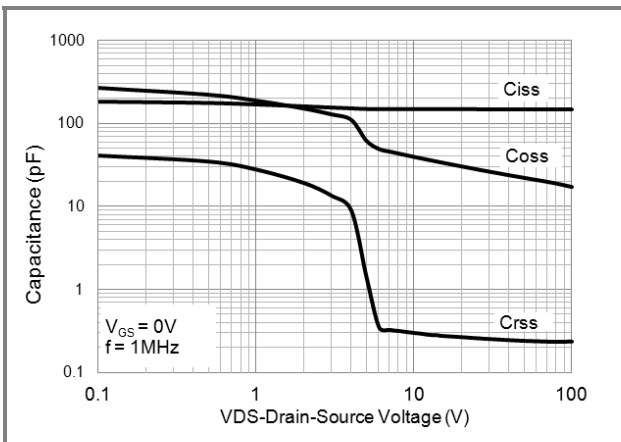


Fig.5 Capacitance vs. Drain-Source Voltage

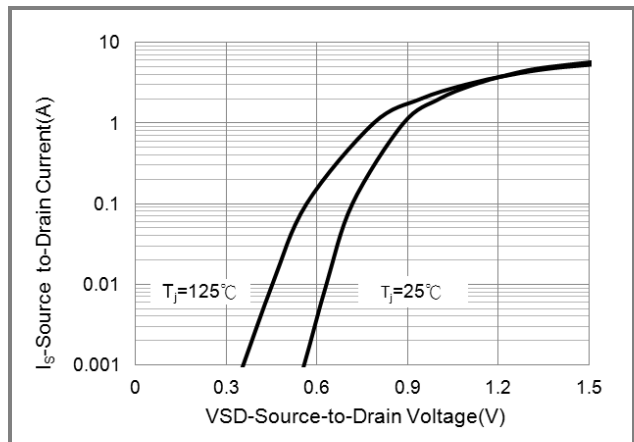


Fig.6 Source-Drain Diode Forward Voltage



# PJN1NA60A / PJW1NA60A / PJU1NA60A / PJD1NA60A

## TYPICAL CHARACTERISTIC CURVES

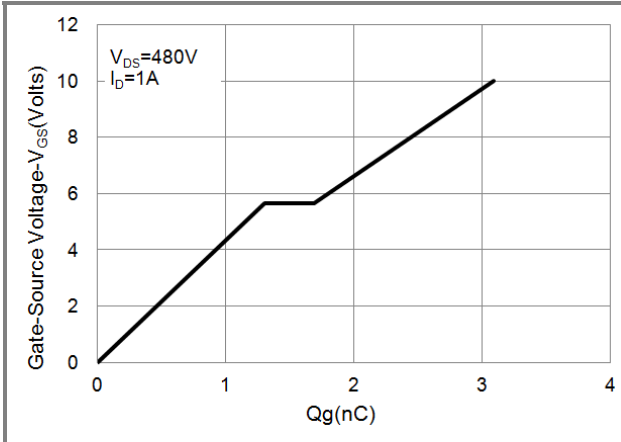


Fig.7 Gate Charge

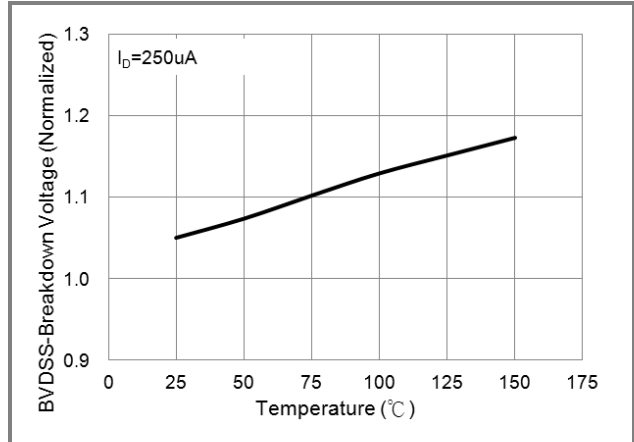


Fig.8 BV<sub>DSS</sub> vs. Junction Temperature

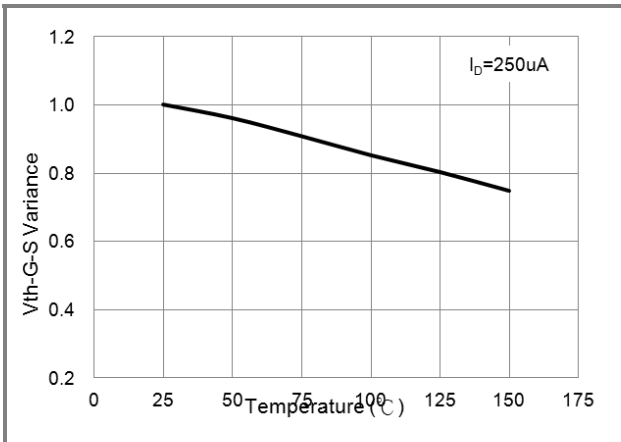


Fig.9 Threshold Voltage Variation with Temperature

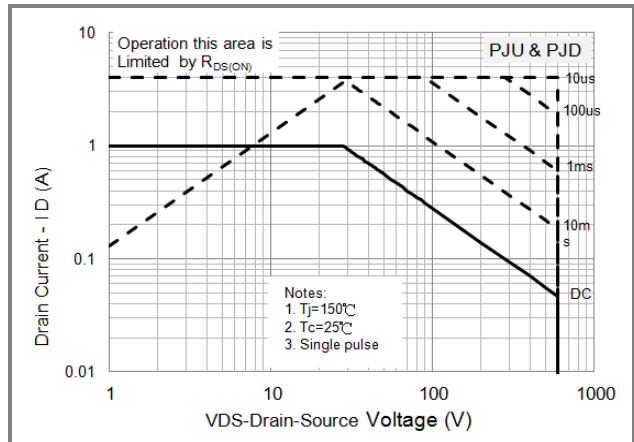


Fig.10 Maximum Safe Operating Area

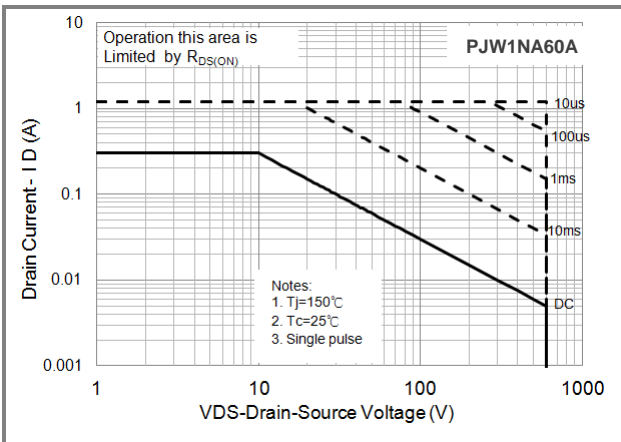


Fig.11 Maximum Safe Operating Area

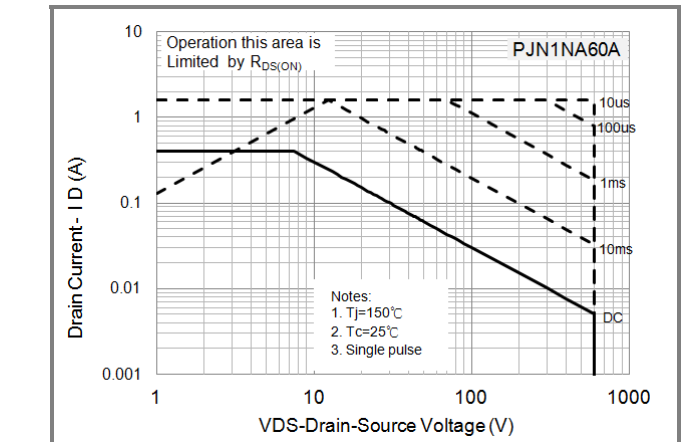


Fig.12 Maximum Safe Operating Area



# PJN1NA60A / PJW1NA60A / PJU1NA60A / PJD1NA60A

## TYPICAL CHARACTERISTIC CURVES

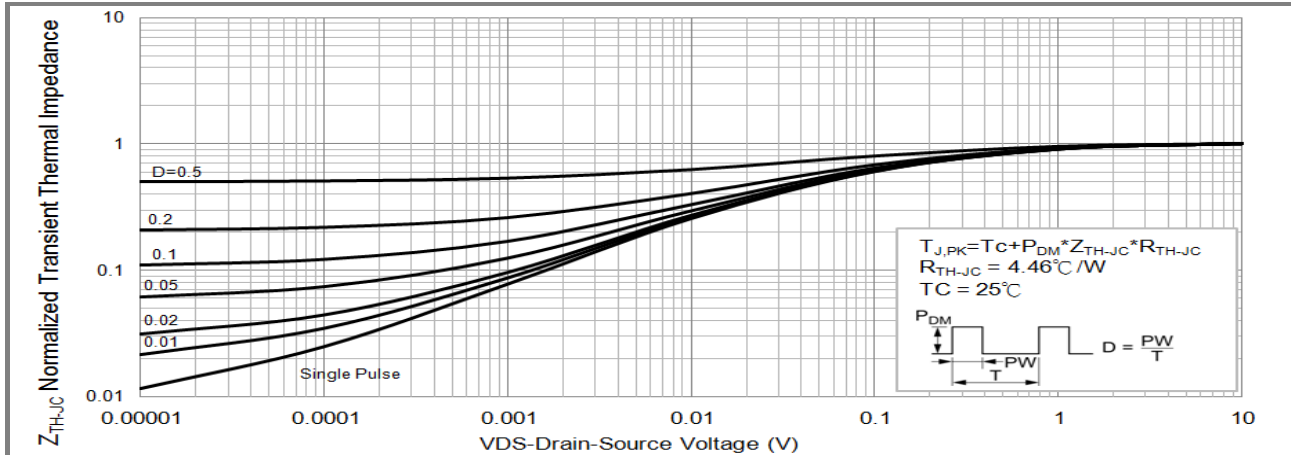


Fig.12 PJU/PJD Normalized Transient Thermal Impedance vs. Pulse Width

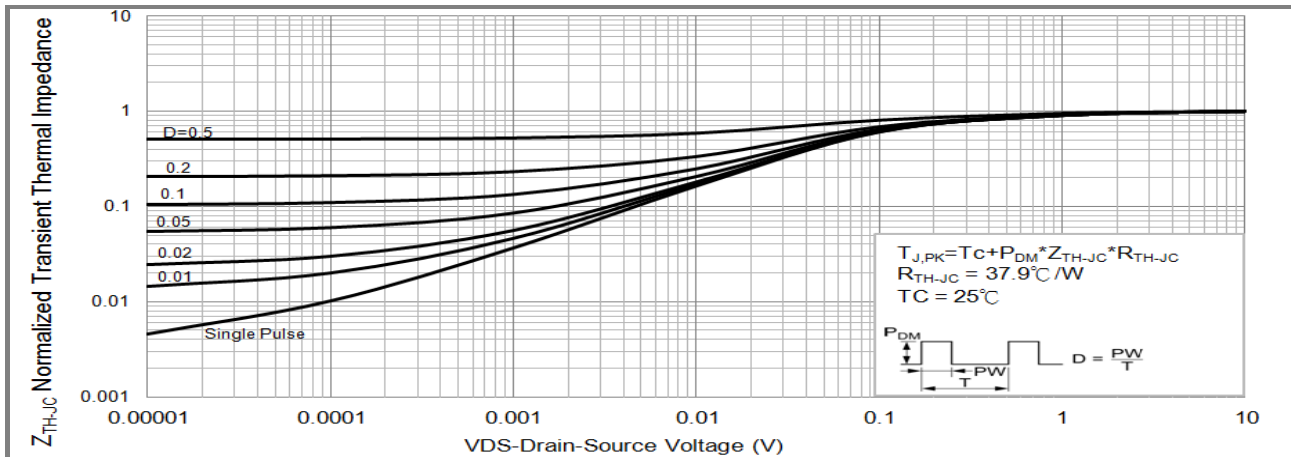


Fig.13 PJW1NA60A Normalized Transient Thermal Impedance vs. Pulse Width

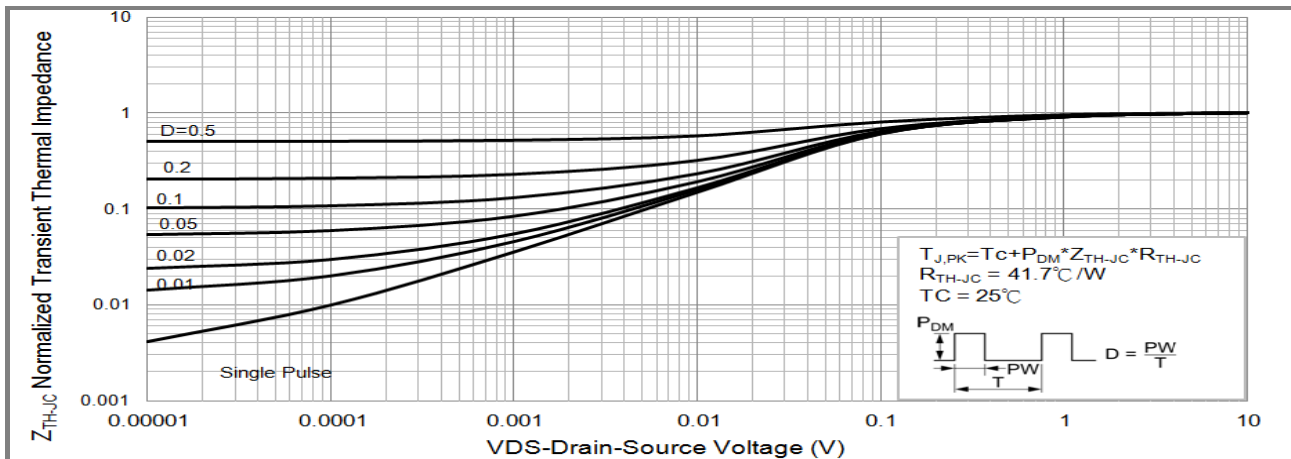
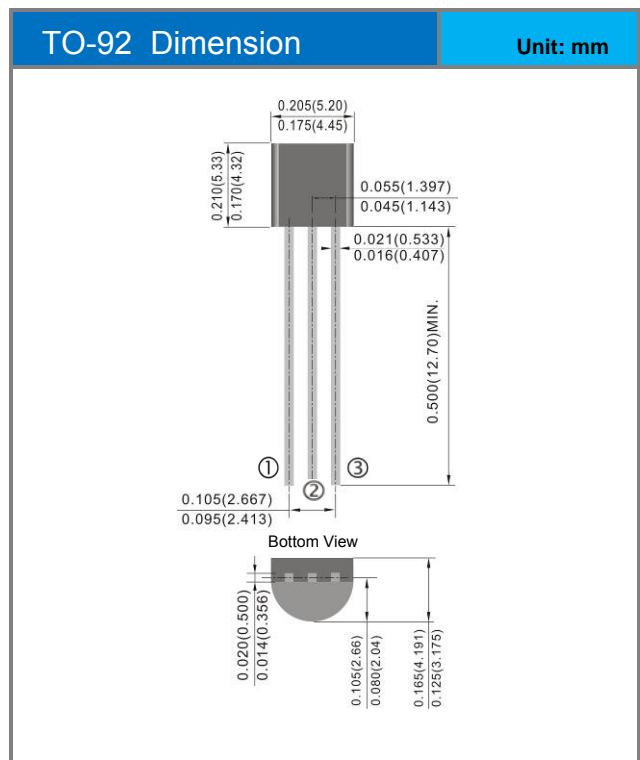
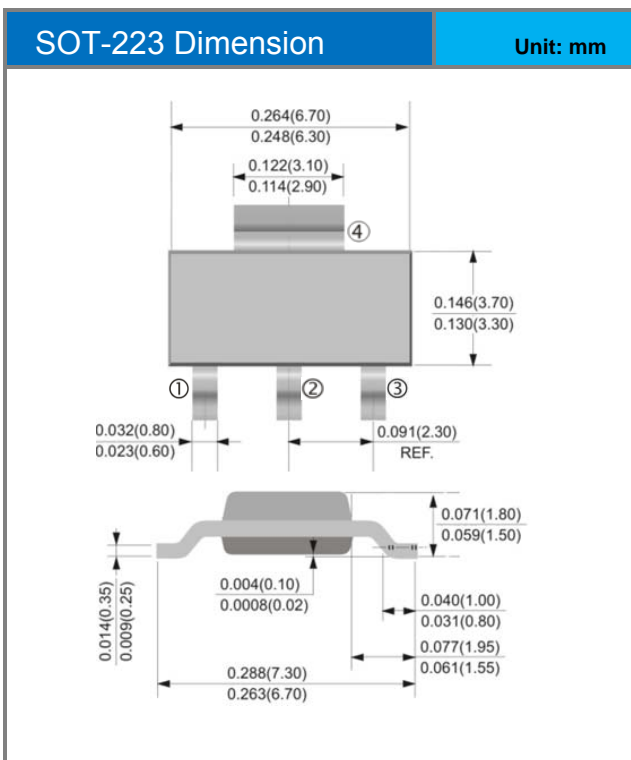
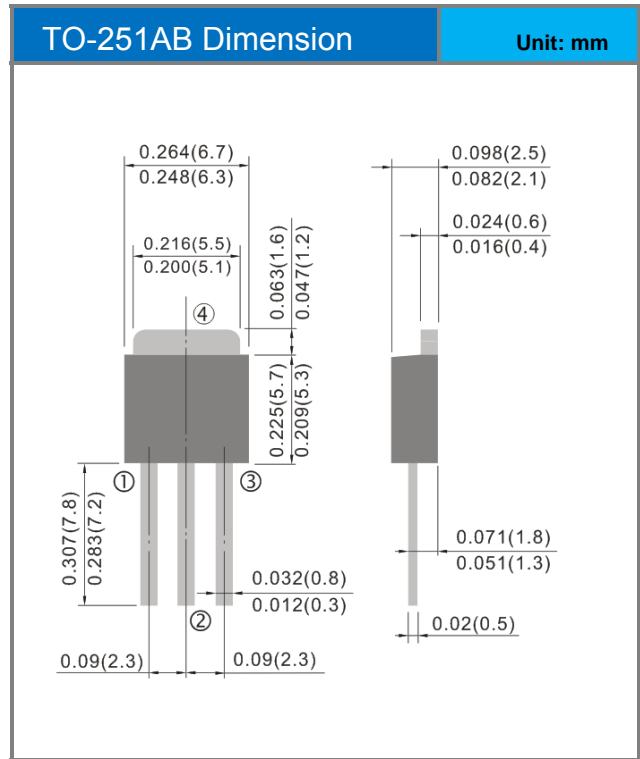
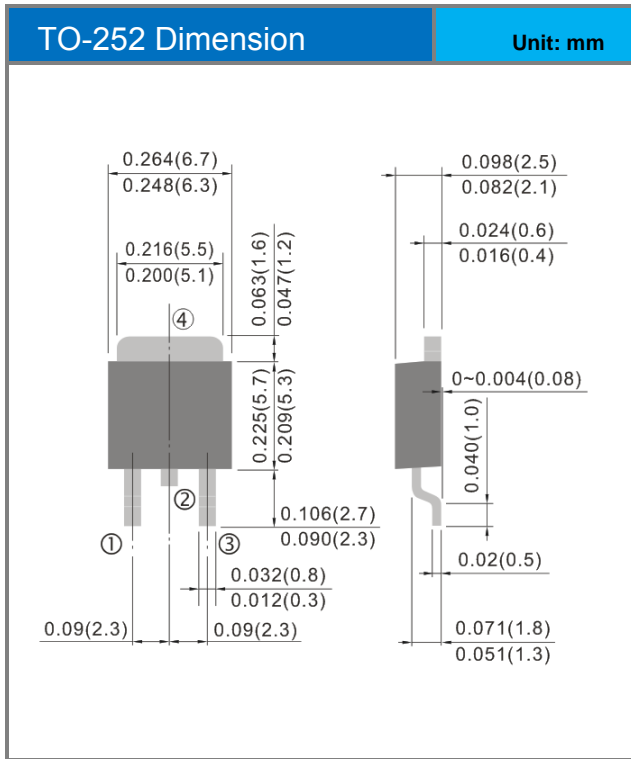


Fig.15 PJN1NA60 Normalized Transient Thermal Impedance vs. Pulse Width



# PJN1NA60A / PJW1NA60A / PJU1NA60A / PJD1NA60A

## Packaging Information





## PJN1NA60A / PJW1NA60A / PJU1NA60A / PJD1NA60A

### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJU1NA60A_TO_00001	TO-251AB	80pcs / Tube	U1NA60A	Halogen free
PJD1NA60A_L2_00001	TO-252	3,000pcs / 13" reel	D1NA60A	Halogen free
PJW1NA60A_R2_00001	SOT-223	2,500pcs / 13" reel	1NA60A	Halogen free
PJN1NA60A_B0_00001	TO-92	1000pcs / bag	1NA60A	Halogen free
PJN1NA60A_A0_00001	TO-92 AMMO	2000pcs / box	1NA60A	Halogen free



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